

This listing of claims will replace all prior versions of claims in the application.

Claim 1. (previously presented) A method for forming a photoresist relief image, comprising:

(a) applying a photoresist composition on a substrate, the photoresist comprising an aromatic resin and a photoactive component, the resin obtainable from reaction of i) a polyol and/or thiol, and ii) and a reactive methylene or keto compound, at least one of the polyol and methylene compound having one or more electronegative substituents, and

(b) exposing the photoresist to activating radiation having a wavelength of less than 300 nm and developing the exposed photoresist layer.

Claim 2. (canceled).

Claim 3. (previously presented) The method of claim 1, wherein the photoresist is exposed with radiation having a wavelength of less than about 260 nm.

Claim 4. (previously presented) The method of claim 1; wherein the photoresist is exposed with radiation having a wavelength of less than about 200 nm.

Claim 5. (previously presented) The method of claim 1; wherein the photoresist is exposed with radiation having a wavelength of about 157 nm.

Claim 6. (previously amended) The method of claim 1 wherein the resin comprises phenolic units.

Claim 7. (previously amended) The method of claim 1 wherein the polyol is an aromatic compound.

Claim 8. (previously amended) The method of claim 1 wherein the polyol is a bisphenol, a polyhydroxybenzene or a polycarboxylic acid compound.

Claim 9. (previously amended) The method of claim 1 wherein the methylene compound or keto compound is a benzyl compound, or an aldehyde substituted with one or more electronegative groups.

Claim 10. (previously amended) The method of claim 1 wherein the resin comprises halogen, halogenated lower alkyl, nitro, cyano, sulfinyl, O-C-O or sulfonyl groups.

Claim 11. (previously amended) The method of claim 1 wherein the resin comprises at least one of fluorine atom, fluorinated lower alkyl, perfluoroalkyl, perfluoroalkylene, fluorinated cycloalkyl, and fluorinated ethers and esters including fluorinated cyclic ethers and esters.

Claim 12. (previously amended) The method of claim 1 wherein the resin comprises acrylate units.

Claim 13. (previously amended) The method of claim 1 wherein the resin is a homopolyacetal.

Claim 14. (previously amended) The method of claim 1 wherein the resin is a copolyacetal.

Claim 15. (previously amended) The method of claim 1 wherein the polymer is chemically amplified positive resist.

Claim 16. (previously amended) The method of claim 1 wherein the polymer is a negative resist.

Claim 17-30. (cancelled)

Claim 31. (currently amended) A method of forming a positive or negative photoresist relief image, comprising:

(a) applying a coating layer of a photoresist ~~composition~~ of claim 17 on a substrate, ~~the photoresist composition comprising a photoactive component and a resin-comprising a polymer that comprises repeat units of:~~

~~1) an active methylene or aldehyde or other carbonyl compound that forms an acetal group in a polymerization or co-polymerization reaction; and~~

~~2) a polyol or thiol that reacts with the methylene or aldehyde or other carbonyl compound to form the acetal group.; and~~

(b) exposing and developing the photoresist layer to yield a positive-tone relief image, ~~wherein the photoresist layer is exposed with radiation having a wavelength of less than about 300 nm.~~

Claims 32-37. (cancelled)